

IN THE CLAIMS

Please amend the claims to read as follows:

Listing of Claims

- 1. (Currently Amended) A battery mounted integrated circuit device, comprising:
 - a semiconductor substrate;
- (2) a solid state battery mounted on said semiconductor substrate;
- (3) an integrated circuit mounted on said semiconductor substrate;
- (4) a first diffusion layer, containing an N-type impurity, formed between a region of said semiconductor substrate where said solid state battery is mounted and an a region of said semiconductor substrate where said integrated circuit is mounted; and
- (5) a second diffusion layer, containing an N-type impurity, formed below said region of said semiconductor substrate where said solid state battery is mounted, and overlapping with said first diffusion layer, wherein:

said solid state battery comprising comprises a positive electrode, a negative electrode, and a solid electrolyte disposed between said positive electrode and said negative electrode,

the concentration of said N-type impurity in said first diffusion layer is higher than the concentration of said N-type impurity in said second diffusion layer, and

at least when said solid state battery is being charged and discharged, said first diffusion layer and said second diffusion layer have a positive potential not less than the potential of the positive electrode with respect to the negative electrode.

- 2. (Original) The battery mounted integrated circuit device in accordance with claim 1, wherein the concentration of said N-type impurity in said first diffusion layer is not less than 1×10^{19} atoms/cm³.
- 3. (Currently Amended) The battery mounted integrated circuit device in accordance with claim 1, wherein the ratio of the concentration of said N-type impurity in said first diffusion layer to the concentration of said N-type impurity in said second diffusion layer is not less than 1×10^1 and not more than 1×10^5 .
 - 4-5. (Canceled).

- 6. (Original) The battery mounted integrated circuit device in accordance with claim 1, wherein said first diffusion layer surrounds said region where said solid state battery is mounted.
- 7. (Original) The battery mounted integrated circuit device in accordance with claim 1, further comprising a wiring layer for connecting said first diffusion layer with the outside.
- 8. (Original) The battery mounted integrated circuit device in accordance with claim 1, further comprising a potential controlling section for controlling a potential to be applied to said first diffusion layer and said second diffusion layer.